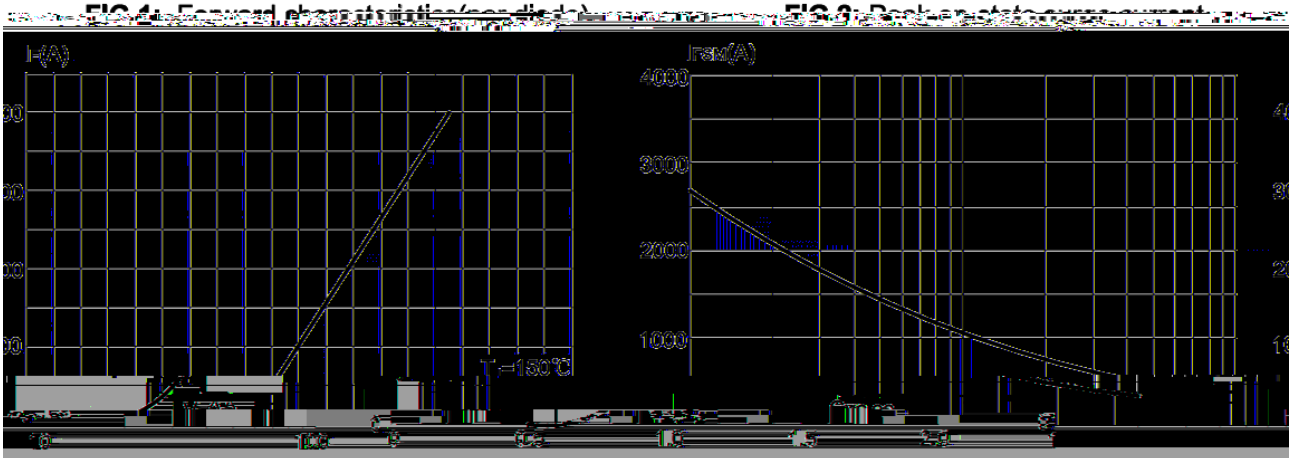
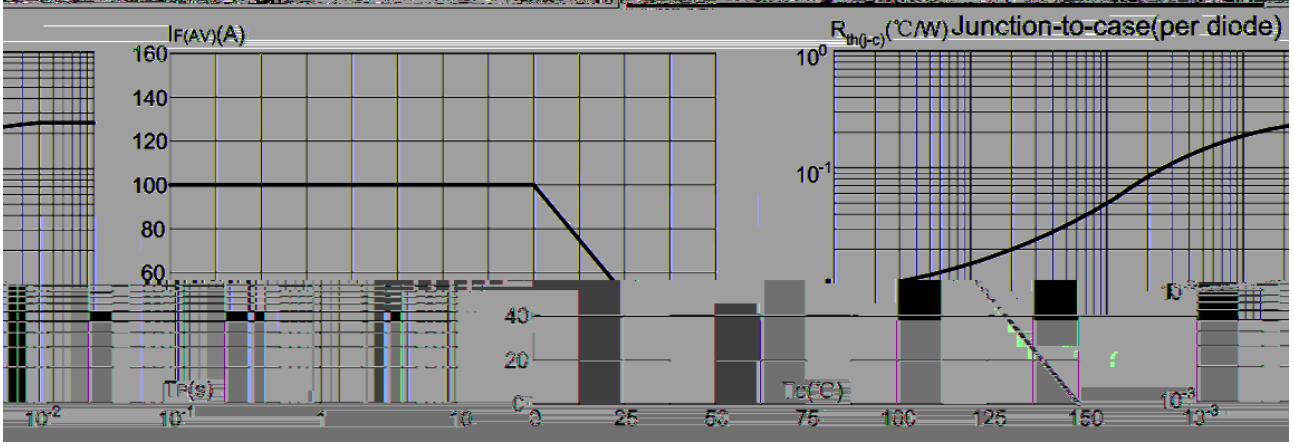
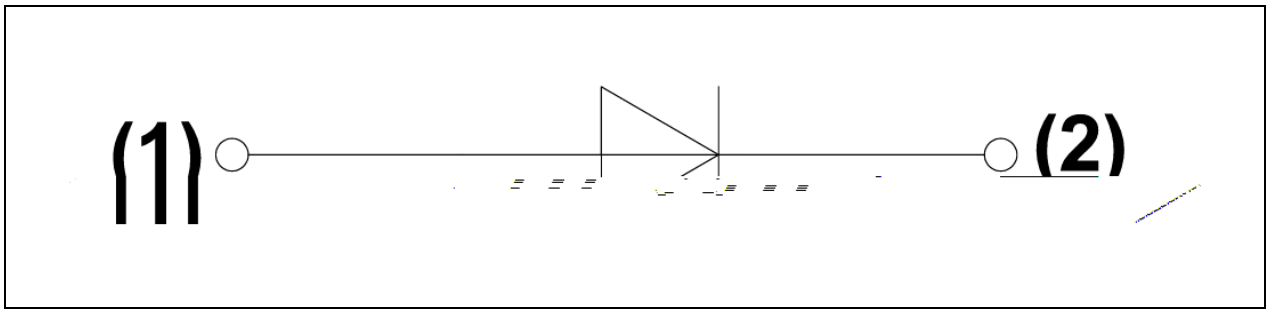

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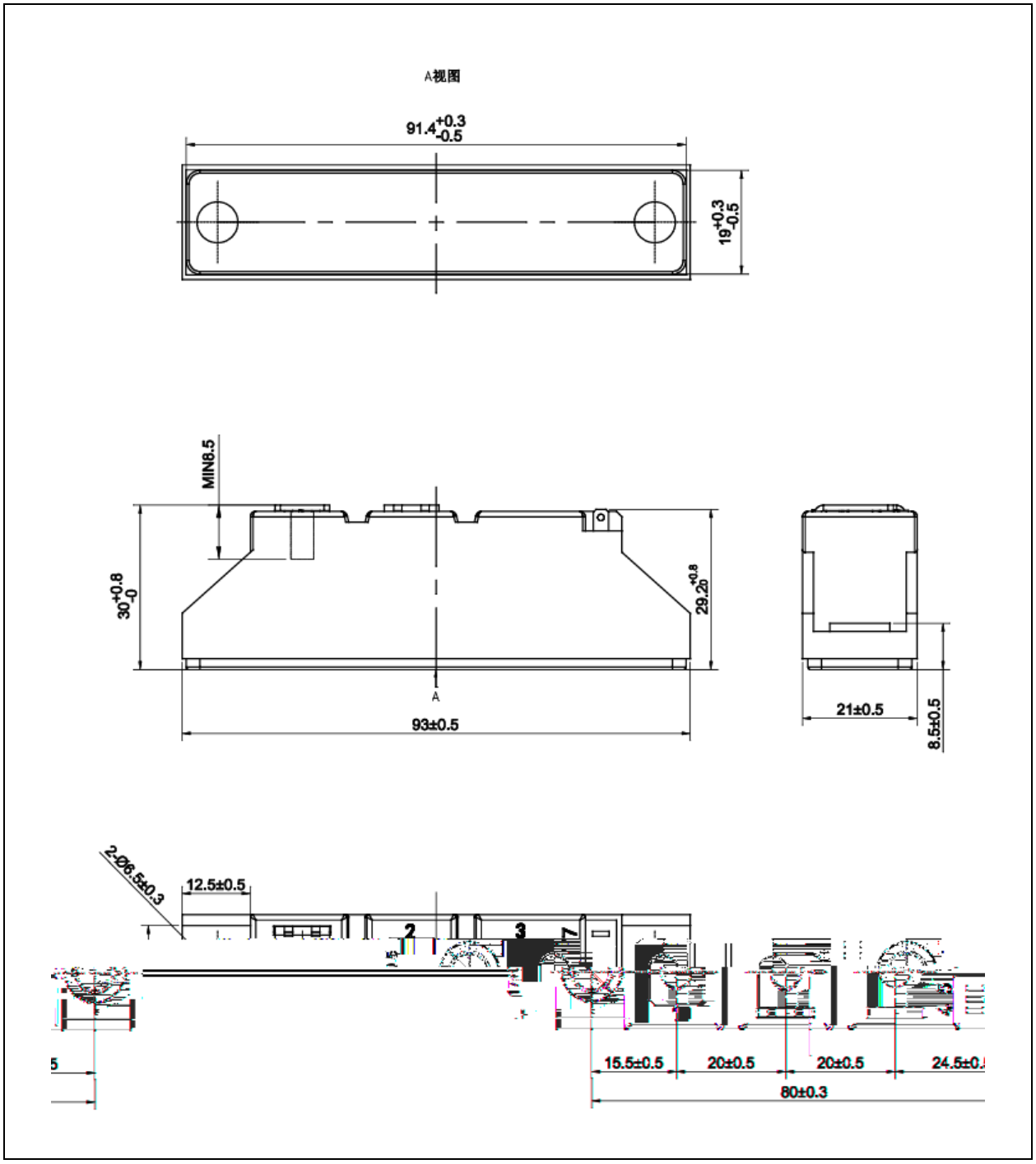
	℃					
	℃					
	℃					
						Ω

			±		


I(A)
IFSM(A)
4000
3000
2000
1000
TJ=150℃


IF(AV)(A)
160
140
120
100
80
60
40
20
0
TP(s)
10-2
10-1
1
10
Rth(j-c)(℃/W)Junction-to-case(per diode)
100
10-1
10-2
10-3
Tc(℃)
0
25
50
75
100
125
150


(1)
(2)


A视图
91.4+0.3 -0.5
19+0.3 -0.5
MIN8.5
30+0.8 -0
29.20+0.8
A
93±0.5
21±0.5
8.5±0.5
2-Ø6.5±0.3
12.5±0.5
2
3
15.5±0.5
20±0.5
20±0.5
80±0.3